

BROADCAST MULTI-BAND RADIO RECEIVER

Features

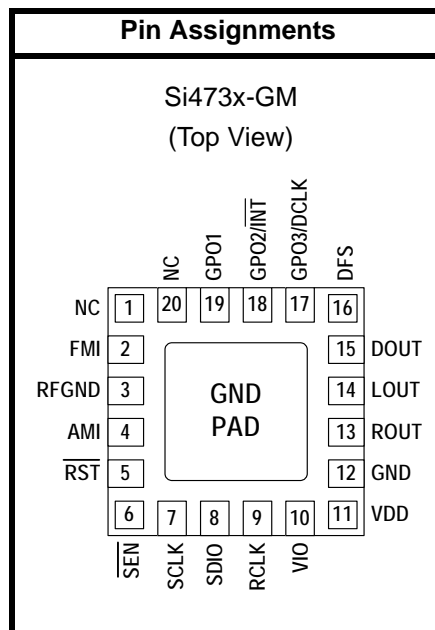
- FM band support: 76–108 MHz
- AM band support: 520–1710 kHz
- SW band support: 2.3–21.85 MHz (Si4734/35)
- LW band support: 153–279 kHz (Si4734/35)
- Weather band support: 162.4–162.55 MHz (Si4736/37/38/39)
- 1050 Hz alert tone detection (Si4736/37/38/39)
- Excellent real-world performance
- Freq synthesizer with integrated VCO
- Advanced seek tuning
- Automatic frequency control (AFC)
- Automatic gain control (AGC)
- Integrated LDO regulator
- Digital FM stereo decoder
- Programmable de-emphasis
- Adaptive noise suppression
- AM/FM digital tuning
- EN55020 compliant
- No manual alignment necessary
- Programmable reference clock
- Volume control
- Programmable soft mute control
- RDS/RBDS processor (Si4731/35/37/39)
- Optional digital audio output (Si4731/35/37/39)
- 2-wire control interface
- 2.7 to 5.5 V supply voltage
- Firmware upgradeable
- Wide range of ferrite loop sticks and air loop antennas supported
- 3 x 3 x 0.55 mm 20-pin QFN package
 - Pb-free/RoHS compliant

Applications

- Table and portable radios
- Audio video receivers
- Stereos
- Mini/micro systems
- CD/DVD players
- Portable media players
- Cellular handsets
- Emergency radios
- Clock radios
- Modules
- Mini HiFi
- Boom boxes

Si473x Product Selector Guide

| Part | FM | AM | RDS | SW/LW | WB |
|--------|--------------|----|-----|-------|----|
| Si4730 | 76 – 108 MHz | ✓ | | | |
| Si4731 | 76 – 108 MHz | ✓ | ✓ | | |
| Si4734 | 64 – 108 MHz | ✓ | | ✓ | |
| Si4735 | 64 – 108 MHz | ✓ | ✓ | ✓ | |
| Si4736 | 76 – 108 MHz | ✓ | | | ✓ |
| Si4737 | 76 – 108 MHz | ✓ | ✓ | | ✓ |
| Si4738 | 76 – 108 MHz | | | | ✓ |
| Si4739 | 76 – 108 MHz | | ✓ | | ✓ |



Patents Pending

Notes:

1. Place Si473x as close as possible to antenna jack and keep the FMI and AMI traces as short as possible.
2. Contact your local sales representatives for more information or to obtain application notes.

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Si473x-B20

1. Product Overview

The Si473x receivers are the industry's first fully-integrated multiband radio receiver ICs from antenna input to audio output. They require minimal external components with no factory alignment. The Si473x receivers reduce the receiver footprint by >90% versus traditional AM/FM solutions. The Si473x also offer best-in-class performance with the most features. The high integration and complete system production test simplifies design-in, increases system quality, and improves manufacturability.

The Si473x receivers include advanced seek algorithms, adjustable soft mute, auto-calibrated digital tuning, and FM stereo processing. In addition, the Si473x ICs provide a programmable reference clock and an I2C-compatible 2-wire control interface.

The Si4731/35/37/39 incorporates a digital processor for the European Radio Data System (RDS) and the North American Radio Broadcast Data System (RBDS), including all required symbol decoding, block synchronization, error detection, and error correction functions. Using these features, the Si4731/35/37/39 enables broadcast data such as station identification and song name to be displayed to the end user.

2. Electrical Specifications

Table 1. Recommended Operating Conditions

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|--------------|----------------|-----|-----|-----|--------------|
| Supply Voltage | V_{DD} | | 2.7 | — | 5.5 | V |
| Interface Supply Voltage | V_{IO} | | 1.5 | — | 3.6 | V |
| Power Supply Powerup Rise Time | V_{DDRISE} | | 10 | — | — | μ s |
| Interface Power Supply Powerup Rise Time | V_{IORISE} | | 10 | — | — | μ s |
| Ambient Temperature | T_A | | -20 | 25 | 85 | $^{\circ}$ C |

Note: All minimum and maximum specifications are guaranteed and apply across the recommended operating conditions. Typical values apply at $V_{DD} = 3.3$ V and 25 $^{\circ}$ C unless otherwise stated. Parameters are tested in production unless otherwise stated.

Table 2. Absolute Maximum Ratings^{1,2}

| Parameter | Symbol | Value | Unit |
|-----------------------------|-----------|----------------------------|----------|
| Supply Voltage | V_{DD} | -0.5 to 5.8 | V |
| Interface Supply Voltage | V_{IO} | -0.5 to 3.9 | V |
| Input Current ³ | I_{IN} | 10 | mA |
| Input Voltage ³ | V_{IN} | -0.3 to ($V_{IO} + 0.3$) | V |
| Operating Temperature | T_{OP} | -40 to 95 | °C |
| Storage Temperature | T_{STG} | -55 to 150 | °C |
| RF Input Level ⁴ | | 0.4 | V_{PK} |

Notes:

1. Permanent device damage may occur if the above Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions as specified in the operational sections of this data sheet. Exposure beyond recommended operating conditions for extended periods may affect device reliability.
2. The Si473x devices are high-performance RF integrated circuits with certain pins having an ESD rating of < 2 kV HBM. Handling and assembly of these devices should only be done at ESD-protected workstations.
3. For input pins SCLK, SEN, SDIO, RST, RCLK, DCLK, DFS, GPO1, GPO2, and GPO3.
4. At RF input pins, FMI and AMI.

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Table 3. DC Characteristics

($V_{DD} = 2.7$ to 5.5 V, $V_{IO} = 1.5$ to 3.6 V, $T_A = -20$ to 85 °C)

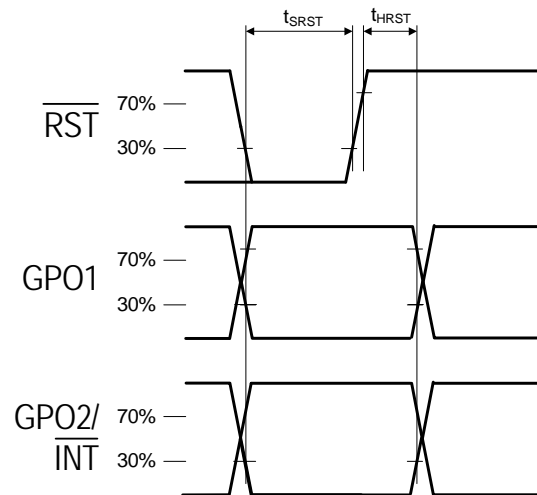
| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|------------|-------------------------------------|---------------------|------|---------------------|---------|
| FM Mode | | | | | | |
| Supply Current | I_{FM} | | — | 19.2 | 22 | mA |
| Supply Current ¹ | I_{FM} | Low SNR level | — | 19.8 | 23 | mA |
| RDS Supply Current ² | I_{FM} | | — | 19.9 | 23 | mA |
| WB Mode (Si4736/37/38/39 only) | | | | | | |
| Supply Current | I_{FM} | | — | 19.2 | 22 | mA |
| Supply Current ¹ | I_{FM} | Low SNR level | — | 19.8 | 23 | mA |
| AM Mode (Si4730/31/34/35/36/37 only) | | | | | | |
| Supply Current | I_{AM} | | — | 17.3 | 20.5 | mA |
| Supplies and Interface | | | | | | |
| Interface Supply Current | I_{IO} | | — | 320 | 600 | μ A |
| V_{DD} Powerdown Current | I_{DDPD} | | — | 10 | 20 | μ A |
| V_{IO} Powerdown Current | I_{IOPD} | SCLK, RCLK inactive | — | 1 | 10 | μ A |
| High Level Input Voltage ³ | V_{IH} | | $0.7 \times V_{IO}$ | — | $V_{IO} + 0.3$ | V |
| Low Level Input Voltage ³ | V_{IL} | | -0.3 | — | $0.3 \times V_{IO}$ | V |
| High Level Input Current ³ | I_{IH} | $V_{IN} = V_{IO} = 3.6$ V | -10 | — | 10 | μ A |
| Low Level Input Current ³ | I_{IL} | $V_{IN} = 0$ V, $V_{IO} = 3.6$ V | -10 | — | 10 | μ A |
| High Level Output Voltage ⁴ | V_{OH} | $I_{OUT} = 500$ μ A | $0.8 \times V_{IO}$ | — | — | V |
| Low Level Output Voltage ⁴ | V_{OL} | $I_{OUT} = -500$ μ A | — | — | $0.2 \times V_{IO}$ | V |
| Notes: | | | | | | |
| 1. LNA is automatically switched to higher current mode for optimum sensitivity in weak signal conditions. | | | | | | |
| 2. Specifications are guaranteed by characterization. | | | | | | |
| 3. For input pins SCLK, SEN, SDIO, RST, RCLK, DCLK, and DFS. | | | | | | |
| 4. For output pins SDIO, DOUT, GPO1, GPO2, and GPO3. | | | | | | |

Table 4. Reset Timing Characteristics^{1,2}(V_{DD} = 2.7 to 5.5 V, V_{IO} = 1.5 to 3.6 V, T_A = -20 to 85 °C)

| Parameter | Symbol | Min | Typ | Max | Unit |
|--|-------------------|-----|-----|-----|------|
| $\overline{\text{RST}}$ Pulse Width and GPO1, GPO2/ $\overline{\text{INT}}$ Setup to $\overline{\text{RST}}\uparrow^3$ | t _{SRST} | 100 | — | — | μs |
| GPO1, GPO2/ $\overline{\text{INT}}$ Hold from $\overline{\text{RST}}\uparrow$ | t _{HRST} | 30 | — | — | ns |

Important Notes:

1. When selecting 2-wire mode, the user must ensure that a 2-wire start condition (falling edge of SDIO while SCLK is high) does not occur within 300 ns before the rising edge of $\overline{\text{RST}}$.
2. When selecting 2-wire mode, the user must ensure that SCLK is high during the rising edge of $\overline{\text{RST}}$, and stays high until after the first start condition.
3. If GPO1 and GPO2 are actively driven by the user, then minimum t_{SRST} is only 30 ns. If GPO1 or GPO2 is hi-Z, then minimum t_{SRST} is 100 μs to provide time for on-chip 1 MΩ devices (active while $\overline{\text{RST}}$ is low) to pull GPO1 high and GPO2 low.

**Figure 1. Reset Timing Parameters for Busmode Select**

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Table 5. 2-Wire Control Interface Characteristics^{1,2,3}

($V_{DD} = 2.7$ to 5.5 V, $V_{IO} = 1.5$ to 3.6 V, $T_A = -20$ to 85 °C)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---|--------------------------|----------------|----------------------------|-----|-----|---------|
| SCLK Frequency | f_{SCL} | | 0 | — | 400 | kHz |
| SCLK Low Time | t_{LOW} | | 1.3 | — | — | μ s |
| SCLK High Time | t_{HIGH} | | 0.6 | — | — | μ s |
| SCLK Input to SDIO \downarrow Setup (START) | $t_{SU:STA}$ | | 0.6 | — | — | μ s |
| SCLK Input to SDIO \downarrow Hold (START) | $t_{HD:STA}$ | | 0.6 | — | — | μ s |
| SDIO Input to SCLK \uparrow Setup | $t_{SU:DAT}$ | | 100 | — | — | ns |
| SDIO Input to SCLK \downarrow Hold ^{4,5} | $t_{HD:DAT}$ | | 0 | — | 900 | ns |
| SCLK input to SDIO \uparrow Setup (STOP) | $t_{SU:STO}$ | | 0.6 | — | — | μ s |
| STOP to START Time | t_{BUF} | | 1.3 | — | — | μ s |
| SDIO Output Fall Time | $t_{f:OUT}$ | | $20 + 0.1 \frac{C_b}{1pF}$ | — | 250 | ns |
| SDIO Input, SCLK Rise/Fall Time | $t_{f:IN}$ $t_{r:IN}$ | | $20 + 0.1 \frac{C_b}{1pF}$ | — | 300 | ns |
| SCLK, SDIO Capacitive Loading | C_b | | — | — | 50 | pF |
| Input Filter Pulse Suppression | t_{SP} | | — | — | 50 | ns |

Notes:

1. When $V_{IO} = 0$ V, SCLK and SDIO are low impedance.
2. When selecting 2-wire mode, the user must ensure that a 2-wire start condition (falling edge of SDIO while SCLK is high) does not occur within 300 ns before the rising edge of \overline{RST} .
3. When selecting 2-wire mode, the user must ensure that SCLK is high during the rising edge of \overline{RST} , and stays high until after the first start condition.
4. The Si473x delays SDIO by a minimum of 300 ns from the V_{IH} threshold of SCLK to comply with the minimum $t_{HD:DAT}$ specification.
5. The maximum $t_{HD:DAT}$ has only to be met when $f_{SCL} = 400$ kHz. At frequencies below 400 KHz, $t_{HD:DAT}$ may be violated as long as all other timing parameters are met.

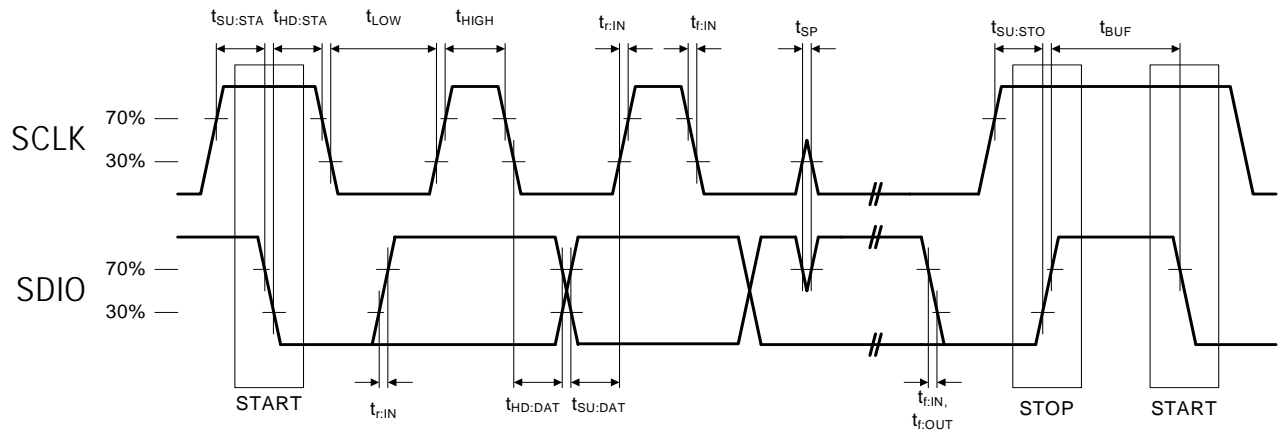


Figure 2. 2-Wire Control Interface Read and Write Timing Parameters

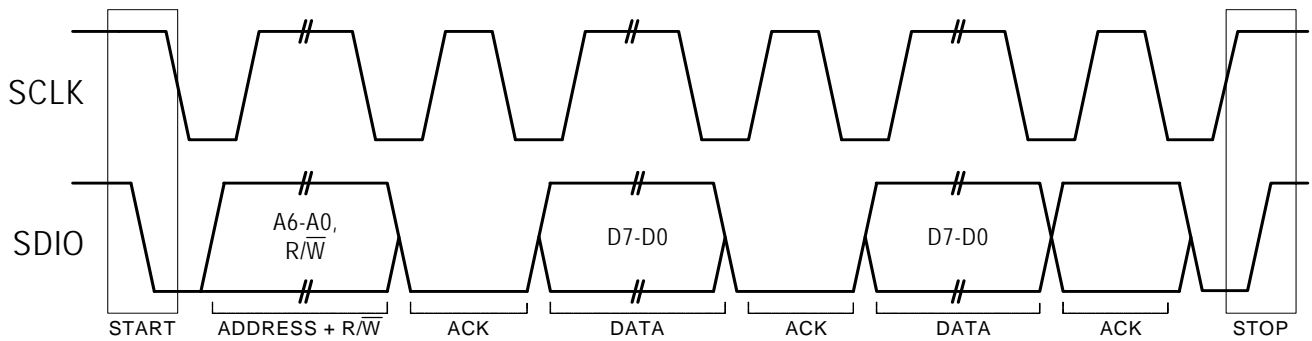


Figure 3. 2-Wire Control Interface Read and Write Timing Diagram

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Table 6. Digital Audio Interface Characteristics

($V_{DD} = 2.7$ to 5.5 V, $V_{IO} = 1.5$ to 3.6 V, $T_A = -20$ to 85 °C)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|----------------|----------------|-----|-----|------|------|
| DCLK Cycle Time | t_{DCT} | | 26 | — | 1000 | ns |
| DCLK Pulse Width High | t_{DCH} | | 10 | — | — | ns |
| DCLK Pulse Width Low | t_{DCL} | | 10 | — | — | ns |
| DFS Set-up Time to DCLK Rising Edge | $t_{SU:DFS}$ | | 5 | — | — | ns |
| DFS Hold Time from DCLK Rising Edge | $t_{HD:DFS}$ | | 5 | — | — | ns |
| DOOUT Propagation Delay from DCLK Falling Edge | $t_{PD:DOOUT}$ | | 0 | — | 12 | ns |

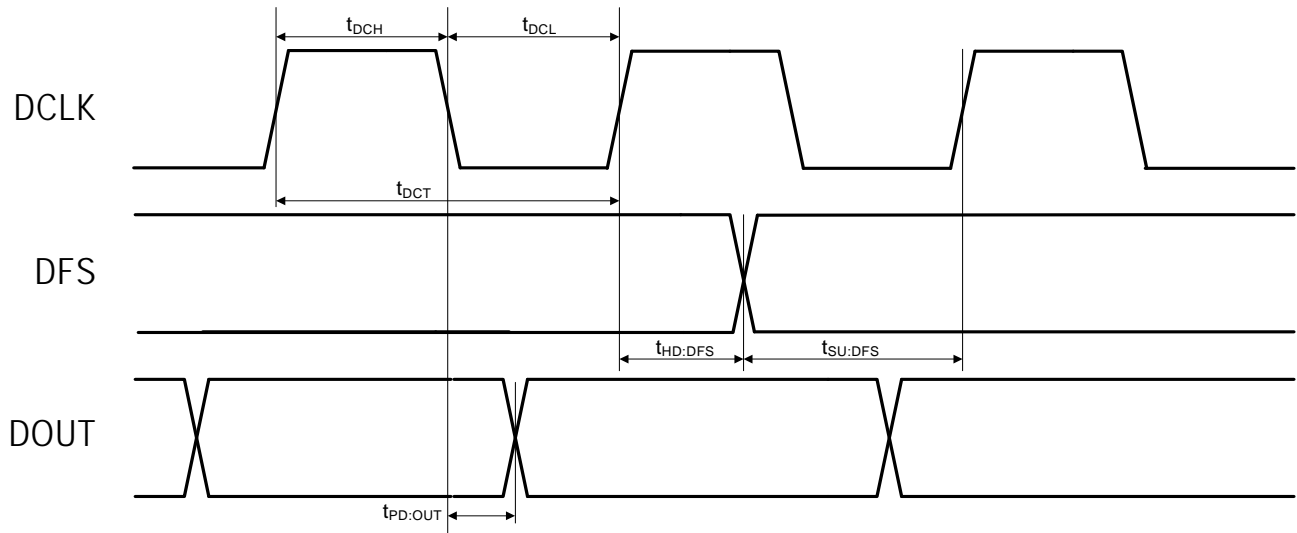


Figure 4. Digital Audio Interface Timing Parameters, I²S Mode

Table 7. FM Receiver Characteristics^{1,2}(V_{DD} = 2.7 to 5.5 V, V_{IO} = 1.5 to 3.6 V, T_A = -20 to 85 °C)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---|-----------------|------------------------------|-----|-----|-----|-------------------|
| Input Frequency | f _{RF} | | 76 | — | 108 | MHz |
| Sensitivity with Headphone Network ^{3,4,5} | | (S+N)/N = 26 dB | — | 2.2 | 3.5 | μV EMF |
| Sensitivity with 50 Ω Network ^{3,4,5,6} | | (S+N)/N = 26 dB | — | 1.1 | — | μV EMF |
| RDS Sensitivity ⁶ | | Δf = 2 kHz, RDS BLER < 5% | — | 15 | — | μV EMF |
| LNA Input Resistance ^{6,7} | | | 3 | 4 | 5 | kΩ |
| LNA Input Capacitance ^{6,7} | | | 4 | 5 | 6 | pF |
| Input IP3 ^{6,8} | | | 100 | 105 | — | dBμV EMF |
| AM Suppression ^{3,4,6,7} | | m = 0.3 | 40 | 50 | — | dB |
| Adjacent Channel Selectivity | | ±200 kHz | 35 | 50 | — | dB |
| Alternate Channel Selectivity | | ±400 kHz | 60 | 70 | — | dB |
| Spurious Response Rejection ⁶ | | In-band | 35 | — | — | dB |
| Audio Output Voltage ^{3,4,7} | | | 72 | 80 | 90 | mV _{RMS} |
| Audio Output L/R Imbalance ^{3,7,9} | | | — | — | 1 | dB |
| Audio Frequency Response Low ⁶ | | -3 dB | — | — | 30 | Hz |
| Audio Frequency Response High ⁶ | | -3 dB | 15 | — | — | kHz |
| Audio Stereo Separation ^{7,9} | | | 25 | — | — | dB |
| Audio Mono S/N ^{3,4,5,7,10} | | | 55 | 63 | — | dB |
| Audio Stereo S/N ^{4,5,7,10,11} | | | — | 58 | — | dB |
| Audio THD ^{3,7,9} | | | — | 0.1 | 0.5 | % |
| De-emphasis Time Constant ⁶ | | FM_DEEMPHASIS = 2 | 70 | 75 | 80 | μs |
| | | FM_DEEMPHASIS = 1 | 45 | 50 | 54 | μs |
| Audio Output Load Resistance ^{6,10} | R _L | Single-ended | 10 | — | — | kΩ |
| Audio Output Load Capacitance ^{6,10} | C _L | Single-ended | — | — | 50 | pF |

Notes:

1. Additional testing information is available in “AN388: Si470x/1x/2x/3x/4x Evaluation Test Board Procedure.” Volume = maximum for all tests. Tested at RF = 98.1 MHz.
2. To ensure proper operation and receiver performance, follow the guidelines in “AN383: Si47xx Antenna, Schematic, Layout and Design Guidelines.” Silicon Laboratories will evaluate schematics and layouts for qualified customers.
3. F_{MOD} = 1 kHz, 75 μs de-emphasis, MONO = enabled, and L = R unless noted otherwise.
4. Δf = 22.5 kHz.
5. B_{AF} = 300 Hz to 15 kHz, A-weighted.
6. Guaranteed by characterization.
7. V_{EMF} = 1 mV.
8. |f₂ - f₁| > 2 MHz, f₀ = 2 x f₁ - f₂. AGC is disabled.
9. Δf = 75 kHz.
10. At L_{OUT} and R_{OUT} pins.
11. Analog audio output mode.
12. At temperature (25°C).

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Table 7. FM Receiver Characteristics^{1,2} (Continued)

($V_{DD} = 2.7$ to 5.5 V, $V_{IO} = 1.5$ to 3.6 V, $T_A = -20$ to 85 °C)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|-----------------------------|--------|--|-----|-----|-----|------------|
| Seek/Tune Time ⁶ | | RCLK tolerance = 100 ppm | — | — | 80 | ms/channel |
| Powerup Time ⁶ | | From powerdown | — | — | 110 | ms |
| RSSI Offset ¹² | | Input levels of 8 and 60 dB μ V at RF Input | -3 | — | 3 | dB |

Notes:

1. Additional testing information is available in "AN388: Si470x/1x/2x/3x/4x Evaluation Test Board Procedure."
Volume = maximum for all tests. Tested at RF = 98.1 MHz.
2. To ensure proper operation and receiver performance, follow the guidelines in "AN383: Si47xx Antenna, Schematic, Layout and Design Guidelines." Silicon Laboratories will evaluate schematics and layouts for qualified customers.
3. $F_{MOD} = 1$ kHz, 75 μ s de-emphasis, MONO = enabled, and L = R unless noted otherwise.
4. $\Delta f = 22.5$ kHz.
5. $B_{AF} = 300$ Hz to 15 kHz, A-weighted.
6. Guaranteed by characterization.
7. $V_{EMF} = 1$ mV.
8. $|f_2 - f_1| > 2$ MHz, $f_0 = 2 \times f_1 - f_2$. AGC is disabled.
9. $\Delta f = 75$ kHz.
10. At L_{OUT} and R_{OUT} pins.
11. Analog audio output mode.
12. At temperature (25°C).

Table 8. AM/SW/LW Receiver Characteristics¹(V_{DD} = 2.7 to 5.5 V, V_{IO} = 1.5 to 3.6 V, TA = -20 to 85 °C)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|-----------------|---|-----|------|-------|-------------------|
| Input Frequency | f _{RF} | Long Wave (LW) | 153 | — | 279 | kHz |
| | | Medium Wave (AM) | 520 | — | 1710 | kHz |
| | | Short Wave (SW) | 2.3 | — | 21.85 | MHz |
| Sensitivity ^{2,3,4,5, 6} | | (S+N)/N = 26 dB | — | 25 | 35 | μV EMF |
| Large Signal Voltage Handling ^{5,7} | | THD < 8% | — | 300 | — | mV _{RMS} |
| Power Supply Rejection Ratio | | ΔV _{DD} = 100 mV _{RMS} , 100 Hz | — | 40 | — | dB |
| Audio Output Voltage ^{2,8} | | | 54 | 60 | 67 | mV _{RMS} |
| Audio S/N ^{2,3,4,6,8} | | | 50 | 56 | — | dB |
| Audio THD ^{2,4,8} | | | — | 0.1 | 0.5 | % |
| Antenna Inductance | | Long Wave (LW) | — | 2800 | — | μH |
| | | Medium Wave (AM) | 180 | — | 450 | |
| Powerup Time | | From powerdown | — | — | 110 | ms |

Notes:

1. To ensure proper operation and receiver performance, follow the guidelines in “AN383: Si47xx Antenna, Schematic, Layout and Design Guidelines.” Silicon Laboratories will evaluate schematics and layouts for qualified customers.
2. F_{MOD} = 1 kHz, 30% modulation, A-weighted, 2 kHz channel filter.
3. B_{AF} = 300 Hz to 15 kHz, A-weighted.
4. f_{RF} = 1000 kHz, Δf = 10 kHz.
5. Guaranteed by characterization.
6. Analog audio output mode.
7. See “AN388: Si470X/1X/2X/3X/4X Evaluation Board Test Procedure” for evaluation method.
8. V_{IN} = 5 mV_{rms}.
9. Stray capacitance on antenna and board must be < 10 pF to achieve full tuning range at higher inductance levels.

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Table 9. WB Receiver Characteristics¹

($V_{DD} = 2.7$ to 5.5 V, $V_{IO} = 1.5$ to 3.6 V, $T_A = 25$ °C)

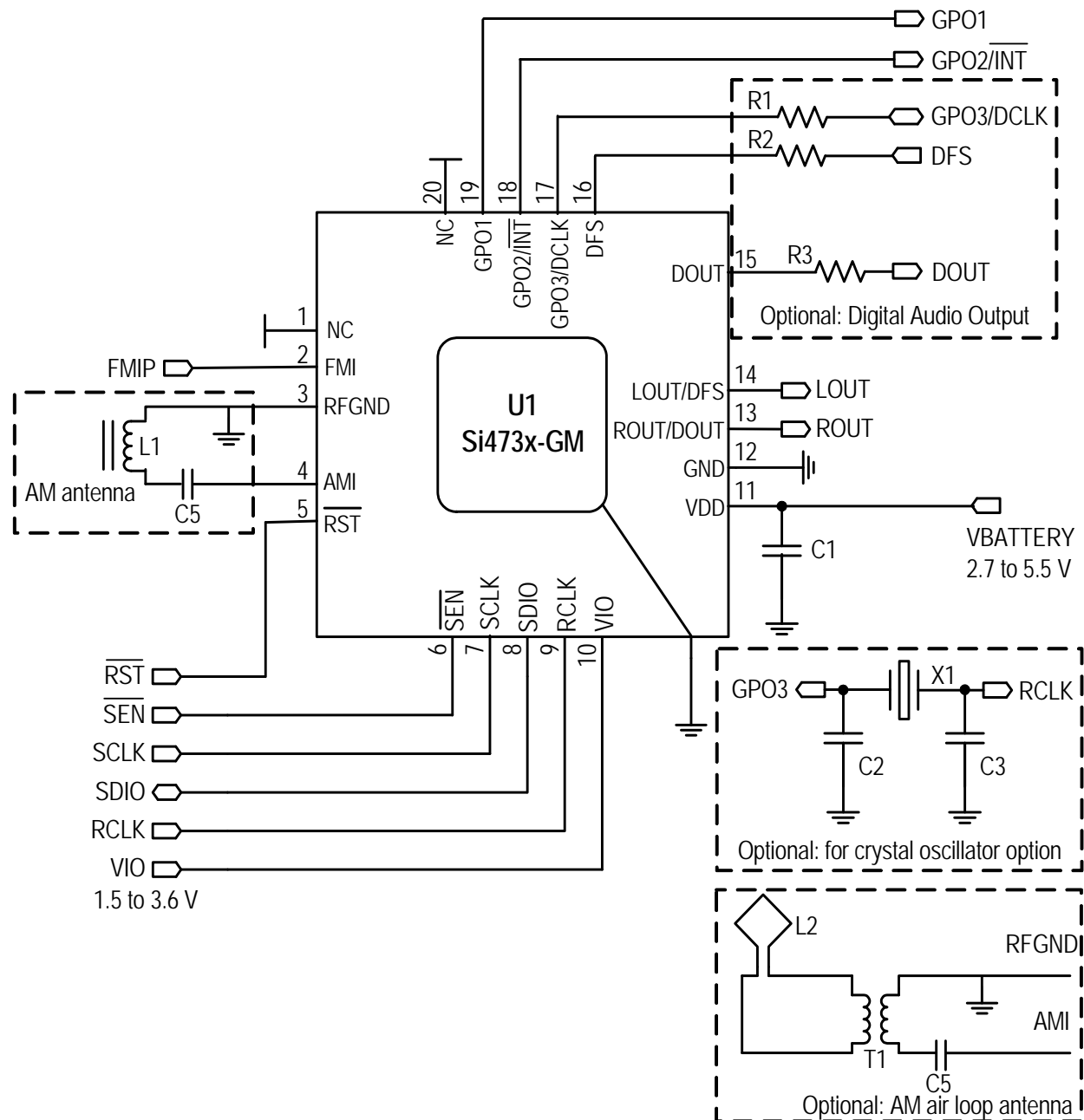
| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|--------|----------------|-------|-----|--------|-------------|
| Input Frequency | f_R | | 162.4 | — | 162.55 | MHz |
| Sensitivity ^{2,3} | | SINAD = 12 dB | — | 0.9 | — | μ V EMF |
| Adjacent Channel Selectivity | | ± 25 kHz | — | 52 | — | dB |
| Audio S/N ^{2,3,4,5} | | Mono | — | 45 | — | dB |
| Audio Frequency Response Low ⁶ | | -3 dB | — | — | 300 | Hz |
| Audio Frequency Response High ⁶ | | -3 dB | 3 | — | — | kHz |
| Notes: | | | | | | |
| <ol style="list-style-type: none"> To ensure proper operation and receiver performance, follow the guidelines in “AN383: Si47xx Antenna, Schematic, Layout and Design Guidelines.” Silicon Laboratories will evaluate schematics and layouts for qualified customers. $F_{MOD} = 1$ kHz. $\Delta f = 3$ kHz. $V_{EMF} = 1$ mV. A-weighted. Guaranteed by characterization | | | | | | |

Table 10. Reference Clock and Crystal Characteristics

($V_{DD} = 2.7$ to 5.5 V, $V_{IO} = 1.5$ to 3.6 V, $T_A = -20$ to 85 °C)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---|--------|----------------|--------|--------|--------|------|
| Reference Clock | | | | | | |
| RCLK Supported Frequencies ¹ | | | 31.130 | 32.768 | 40,000 | kHz |
| RCLK Frequency Tolerance ² | | | -100 | — | 100 | ppm |
| REFCLK_PRESCALE | | | 1 | — | 4095 | |
| REFCLK | | | 31.130 | 32.768 | 34.406 | kHz |
| Crystal Oscillator | | | | | | |
| Crystal Oscillator Frequency | | | — | 32.768 | — | kHz |
| Crystal Frequency Tolerance ² | | | -50 | — | 50 | ppm |
| Board Capacitance | | | — | — | 3.5 | pF |
| Notes: | | | | | | |
| <ol style="list-style-type: none"> The Si473x divides the RCLK input by REFCLK_PRESCALE to obtain REFCLK. There are some RCLK frequencies between 31.130 kHz and 40 MHz that are not supported. See “AN332: Si47xx Programming Guide,” Table 6 for more details. A frequency tolerance of ± 50 ppm is required for FM seek/tune using 50 kHz channel spacing, SW seek/tune, and WB tune. | | | | | | |

3. Typical AM/FM Application Schematic



Notes:

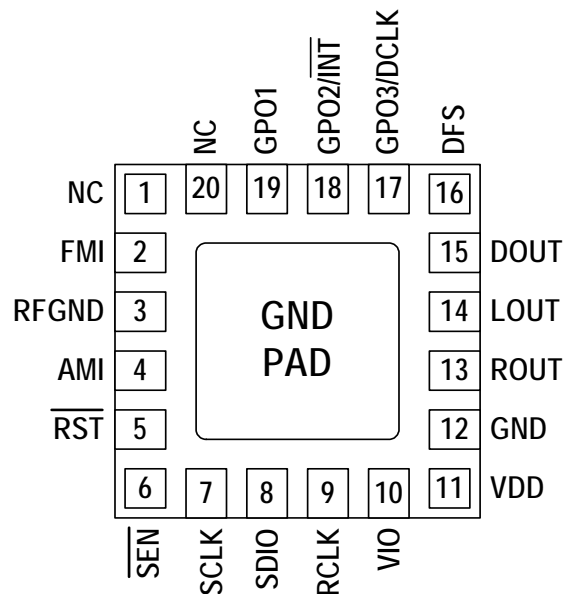
1. Place C1 close to V_{DD} pin.
2. All grounds connect directly to GND plane on PCB.
3. Pins 1 and 20 are no connects, leave floating.
4. To ensure proper operation and receiver performance, follow the guidelines in "AN383: Si47xx Antenna, Schematic, Layout and Design Guidelines." Silicon Laboratories will evaluate schematics and layouts for qualified customers.
5. Pin 2 connects to the FM antenna interface and pin 4 connects to the AM antenna interface.
6. RFGND should be locally isolated from GND.
7. Place Si473x as close as possible to antenna jack and keep the FMI and AMI traces as short as possible.

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4. Bill of Materials

| Component(s) | Value/Description | Supplier |
|----------------------------|--|----------------------|
| C1 | Supply bypass capacitor, 22 nF, $\pm 20\%$, Z5U/X7R | Murata |
| C5 | Coupling capacitor, 0.47 μ F, $\pm 20\%$, Z5U/X7R | Murata |
| L1 | Ferrite loop stick, 180–450 μ H | Jiaxin |
| U1 | Si473x AM/FM Radio Tuner | Silicon Laboratories |
| Optional Components | | |
| T1 | Transformer, 1–5 turns ratio | Jiaxin, UMEC |
| L2 | Air loop antenna, 10–20 μ H | Various |
| C2, C3 | Crystal load capacitors, 22 pF, $\pm 5\%$, COG (Optional: for crystal oscillator option) | Venkel |
| X1 | 32.768 kHz crystal (Optional: for crystal oscillator option) | Epson |
| R1 | Resistor, 2 k Ω (Optional: for digital audio) | Venkel |
| R2 | Resistor, 2 k Ω (Optional: for digital audio) | Venkel |
| R3 | Resistor, 600 Ω (Optional: for digital audio) | Venkel |

5. Pin Descriptions: Si473x-GM



| Pin Number(s) | Name | Description |
|---------------|------------------------------|--|
| 1, 20 | NC | No connect. Leave floating. |
| 2 | FMI | FM/WB/SW RF inputs. FMI should be connected to the antenna trace. |
| 3 | RFGND | RF ground. Connect to ground plane on PCB. |
| 4 | AMI | AM/SW/LW RF input. AMI should be connected to the AM antenna. |
| 5 | $\overline{\text{RST}}$ | Device reset (active low) input. |
| 6 | $\overline{\text{SEN}}$ | Serial enable input (active low). |
| 7 | SCLK | Serial clock input. |
| 8 | SDIO | Serial data input/output. |
| 9 | RCLK | External reference oscillator input. |
| 10 | V_{IO} | I/O supply voltage. |
| 11 | V_{DD} | Supply voltage. May be connected directly to battery. |
| 12, GND PAD | GND | Ground. Connect to ground plane on PCB. |
| 13 | ROUT | Right audio line output in analog output mode. |
| 14 | LOUT | Left audio line output in analog output mode. |
| 15 | DOUT | Digital output data in digital output mode. |
| 16 | DFS | Digital frame synchronization input in digital output mode. |
| 17 | GPO3/DCLK | General purpose output, crystal oscillator, or digital bit synchronous clock input in digital output mode. |
| 18 | $\overline{\text{GPO2/INT}}$ | General purpose output or interrupt pin. |
| 19 | GPO1 | General purpose output. |

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6. Ordering Guide

| Part Number* | Description | Package Type | Operating Temperature |
|---------------|--|----------------|-----------------------|
| Si4730-B20-GM | AM/FM Broadcast Radio Receiver | QFN Pb-free | -20 to 85 °C |
| Si4731-B20-GM | AM/FM Broadcast Radio Receiver with RDS/RBDS | QFN Pb-free | -20 to 85 °C |
| Si4734-B20-GM | AM/FM/SW/LW Broadcast Radio Receiver | QFN Pb-free | -20 to 85 °C |
| Si4735-B20-GM | AM/FM/SW/LW Broadcast Radio Receiver with RDS/RBDS | QFN Pb-free | -20 to 85 °C |
| Si4736-B20-GM | AM/FM/WB Broadcast Radio Receiver | QFN Pb-free | -20 to 85 °C |
| Si4737-B20-GM | AM/FM/WB Broadcast Radio Receiver with RDS/RBDS | QFN Pb-free | -20 to 85 °C |
| Si4738-B20-GM | FM/WB Broadcast Radio Receiver | QFN Pb-free | -20 to 85 °C |
| Si4739-B20-GM | FM/WB Broadcast Radio Receiver with RDS/RBDS | QFN Pb-free | -20 to 85 °C |

***Note:** Add an "(R)" at the end of the device part number to denote tape and reel option; 2500 quantity per reel.

7. Package Outline: Si473x QFN

Figure 5 illustrates the package details for the Si473x. Table 11 lists the values for the dimensions shown in the illustration.

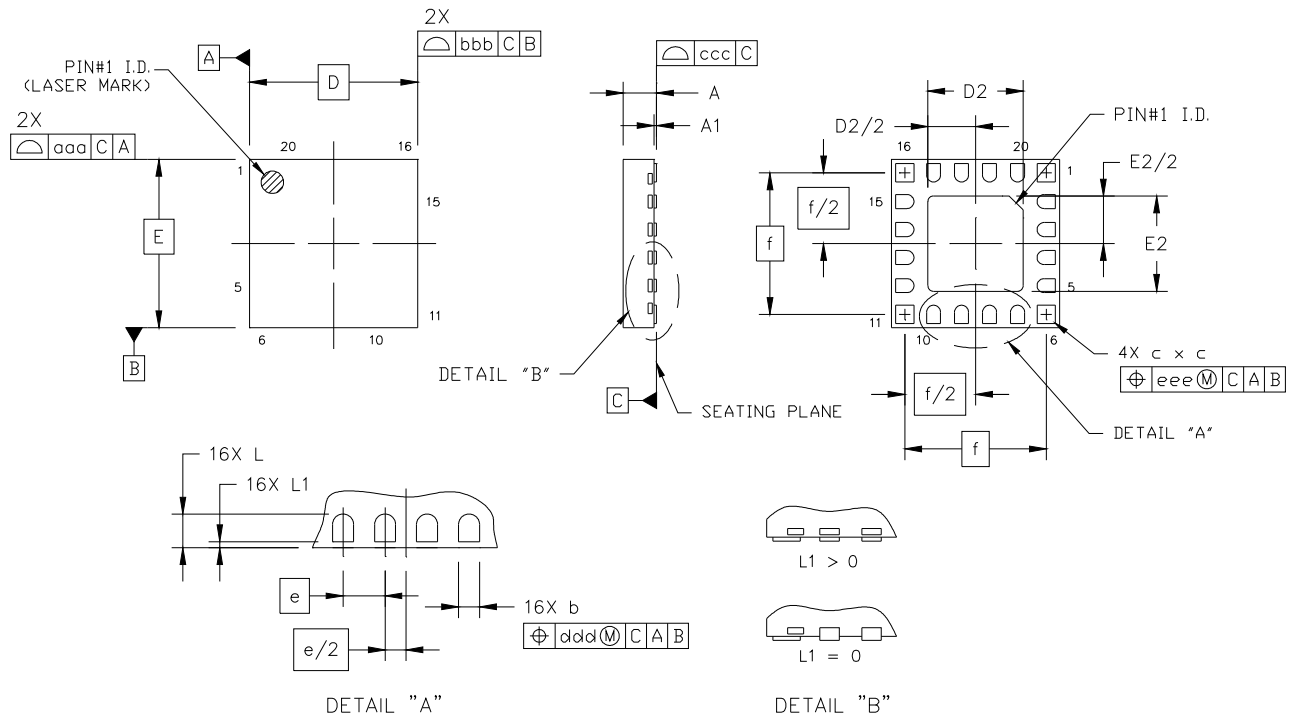


Figure 5. 20-Pin Quad Flat No-Lead (QFN)

Table 11. Package Dimensions

| Symbol | Millimeters | | |
|--------|-------------|------|------|
| | Min | Nom | Max |
| A | 0.50 | 0.55 | 0.60 |
| A1 | 0.00 | 0.02 | 0.05 |
| b | 0.20 | 0.25 | 0.30 |
| c | 0.27 | 0.32 | 0.37 |
| D | 3.00 BSC | | |
| D2 | 1.65 | 1.70 | 1.75 |
| e | 0.50 BSC | | |
| E | 3.00 BSC | | |
| E2 | 1.65 | 1.70 | 1.75 |

| Symbol | Millimeters | | |
|--------|-------------|------|------|
| | Min | Nom | Max |
| f | 2.53 BSC | | |
| L | 0.35 | 0.40 | 0.45 |
| L1 | 0.00 | — | 0.10 |
| aaa | — | — | 0.05 |
| bbb | — | — | 0.05 |
| ccc | — | — | 0.08 |
| ddd | — | — | 0.10 |
| eee | — | — | 0.10 |

Notes:

1. All dimensions are shown in millimeters (mm) unless otherwise noted.
2. Dimensioning and tolerancing per ANSI Y14.5M-1994.

8. PCB Land Pattern: Si473x QFN

Figure 6 illustrates the PCB land pattern details for the Si473x family. Table 12 lists the values for the dimensions shown in the illustration.

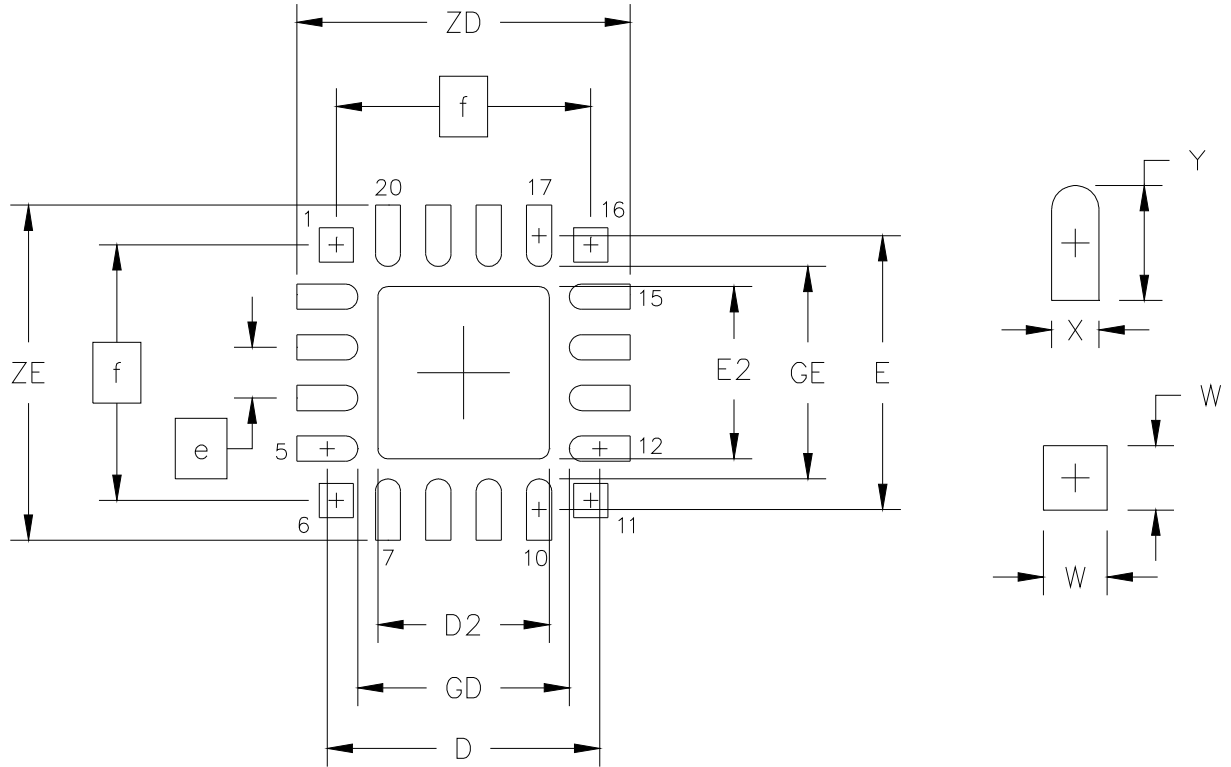


Figure 6. PCB Land Pattern

Table 12. PCB Land Pattern Dimensions

| Symbol | Millimeters | | Symbol | Millimeters | |
|--------|-------------|------|--------|-------------|------|
| | Min | Max | | Min | Max |
| D | 2.71 REF | | GE | 2.10 | — |
| D2 | 1.60 | 1.80 | W | — | 0.34 |
| e | 0.50 BSC | | X | — | 0.28 |
| E | 2.71 REF | | Y | 0.61 REF | |
| E2 | 1.60 | 1.80 | ZE | — | 3.31 |
| f | 2.53 BSC | | ZD | — | 3.31 |
| GD | 2.10 | — | | | |

Notes: General

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on IPC-SM-782 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

Notes: Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μ m minimum, all the way around the pad.

Notes: Stencil Design

1. A stainless steel, laser-cut, and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 1:1 for the perimeter pads.
4. A 1.45 x 1.45 mm square aperture should be used for the center pad. This provides approximately 70% solder paste coverage on the pad, which is optimum to assure correct component stand-off.

Notes: Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

9. Additional Reference Resources

Contact your local sales representatives for more information or to obtain copies of the following references:

- EN55020 Compliance Test Certificate
- AN332: Si47xx Programming Guide
- AN383: Si47xx Antenna, Schematic, Layout, and Design Layout Guidelines
- AN388: Si470x/1x/2x/3x/4x Evaluation Board Test Procedure

NOTES:

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